NSN 5961-01-023-2853

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-023-2853
Inclosure Material:
Plastic
Overall Length:
0.645 inches
Overall Height:
0.135 inches
Overall Width:
0.505 inches
Mounting Facility Quantity:
1
Mounting Method:
Threaded hole
Thread Size:
0.138 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 repetitive peak off-state voltage
Current Rating Per Characteristic:
100.00 amperes forward current, total rms watts
Power Rating Per Characteristic:
10.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Thread Series Designator:
Unc
Terminal Type And Quantity:
3 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0